# imall

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# FDS9933

AIRCHIL

SEMICONDUCTO

### Dual P-Channel 2.5V Specified PowerTrench<sup>®</sup> MOSFET

#### **General Description**

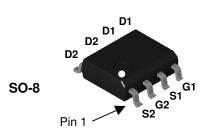
This P-Channel MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 12V).

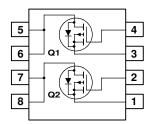
#### Applications

- Load switch
- Motor drive
- DC/DC conversion
- Power management

#### Features

- -5 A, -20 V,  $R_{DS(ON)} = 55 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$  $R_{DS(ON)} = 90 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$
- Extended  $V_{\text{GSS}}$  range (±12V) for battery applications
- Low gate charge
- High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





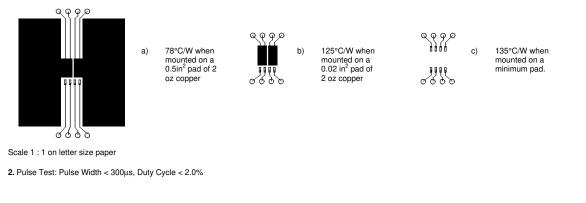
#### Absolute Maximum Ratings TA=25°C unless otherwise noted

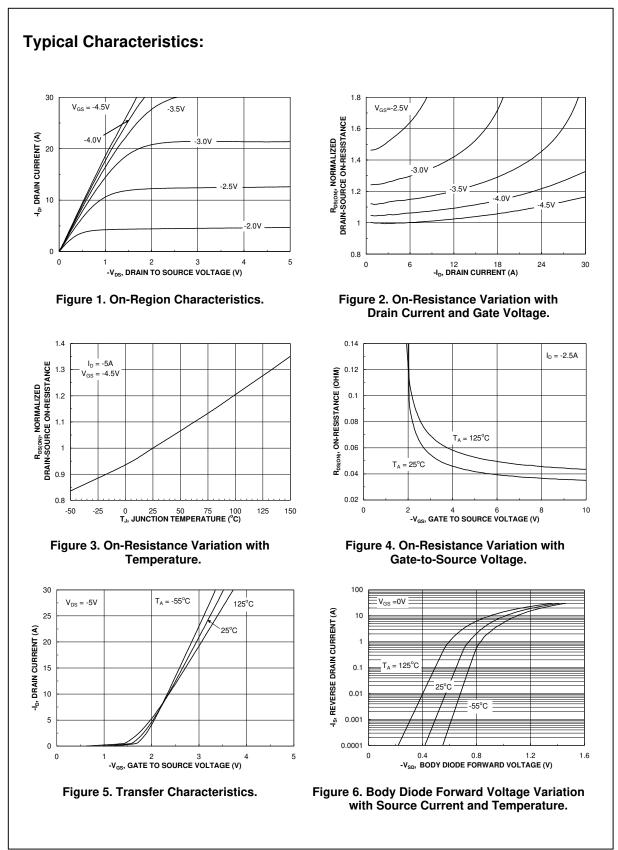
Symbol		Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Sourc	e Voltage		-20	V
V <sub>GSS</sub>	Gate-Sourc	e Voltage		±12	V
ID	Drain Curre	nt – Continuous	(Note 1a)	-5	А
		– Pulsed		-30	
P <sub>D</sub>	Power Dissipation for Dual Operation			2	W
	Power Diss	pation for Single Operation	1 (Note 1a)	1.6	
			(Note 1b)	1	
			(Note 1c)	0.9	
T <sub>J</sub> , T <sub>STG</sub>	Operating a	nd Storage Junction Temp	erature Range	-55 to +175	°C
Therma	I Charac	teristics			
$R_{\theta JA}$	Thermal Re	hermal Resistance, Junction-to-Ambient		78	°C/W
R <sub>eJC</sub>	Thermal Resistance, Junction-to-Case		e (Note 1)	40	°C/W
Packag	e Markin	g and Ordering I	nformation		
Device Marking		Device	Reel Size	Tape width	Quantity
99	33	FDS9933	13"	12mm	2500 units

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FDS9933

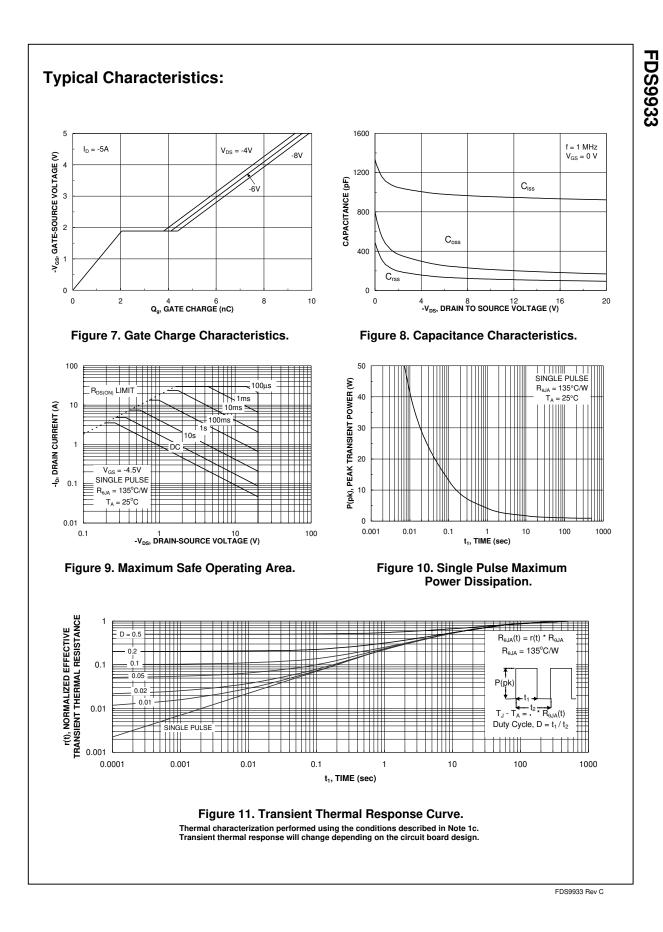
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
<u>ΔBV<sub>DSS</sub></u> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		-12		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -16 V$ , $V_{GS} = 0 V$			-1	μA
I <sub>GSS</sub>	Gate-Body Leakage	$V_{GS} = \pm 12 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{\text{DS}} = V_{\text{GS}}, \ I_{\text{D}} = -250 \ \mu\text{A}$	-0.6	-0.8	-1.2	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		3		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$V_{GS} = -4.5 V$ , $I_D = -3.2 A$ $V_{GS} = -2.5 V$ , $I_D = -1.0 A$		44 72	55 90	mΩ
I <sub>D(on)</sub>	On-State Drain Current		-16			Α
<b>g</b> FS	Forward Transconductance	$V_{DS} = -9 V$ , $I_D = -3.4 A$		8		S
Dvnamic	Characteristics	•				
C <sub>iss</sub>	Input Capacitance	$V_{DS} = -10 \text{ V}, \qquad V_{GS} = 0 \text{ V},$		825		pF
Coss	Output Capacitance	f = 1.0 MHz		420		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			150		pF
Switchin	g Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{\text{DD}} = -10 \ V, \qquad I_{\text{D}} = -1 \ A, \label{eq:VDD}$		16	40	ns
tr	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, \qquad R_{GEN} = 6 \Omega$		46	80	ns
t <sub>d(off)</sub>	Turn-Off Delay Time			40	70	ns
t <sub>f</sub>	Turn-Off Fall Time			25	40	ns
Qg	Total Gate Charge	$V_{DS} = -6 V, I_D = -3.2A,$		10	20	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = -4.5 V$		2.1		nC
Q <sub>gd</sub>	Gate-Drain Charge			3.3		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
Is	Maximum Continuous Drain–Source	Ŭ			-2.0	Α
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_{S} = -2.0 A$ (Note 2)		-0.7	-1.2	V





FDS9933 Rev C

FDS9933



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